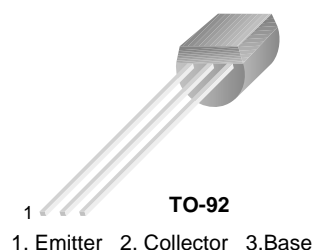


2SA733

PNP General Purpose Amplifier

Features

- This device is designed for general purpose amplifier applications at collector currents to 300 mA.
- Sourced from Process 68.



Absolute Maximum Ratings* $T_A=25^{\circ}\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|----------------|--|-------------|--------------------|
| V_{CBO} | Collector-Base Voltage | -60 | V |
| V_{CEO} | Collector-Emitter Voltage | -50 | V |
| V_{EBO} | Emitter-Base Voltage | -5.0 | V |
| I_C | Collector current - Continuous | -500 | mA |
| T_J, T_{STG} | Operating and Storage Junction Temperature Range | -55 to +150 | $^{\circ}\text{C}$ |

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

| Symbol | Parameter | Max | Units |
|-----------------|---|------------|------------------------------|
| P_D | Total Device Dissipation Derate above 25°C | 625 5.0 | mW mW/ $^{\circ}\text{C}$ |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 83.3 | $^{\circ}\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 200 | $^{\circ}\text{C}/\text{W}$ |

Electrical Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

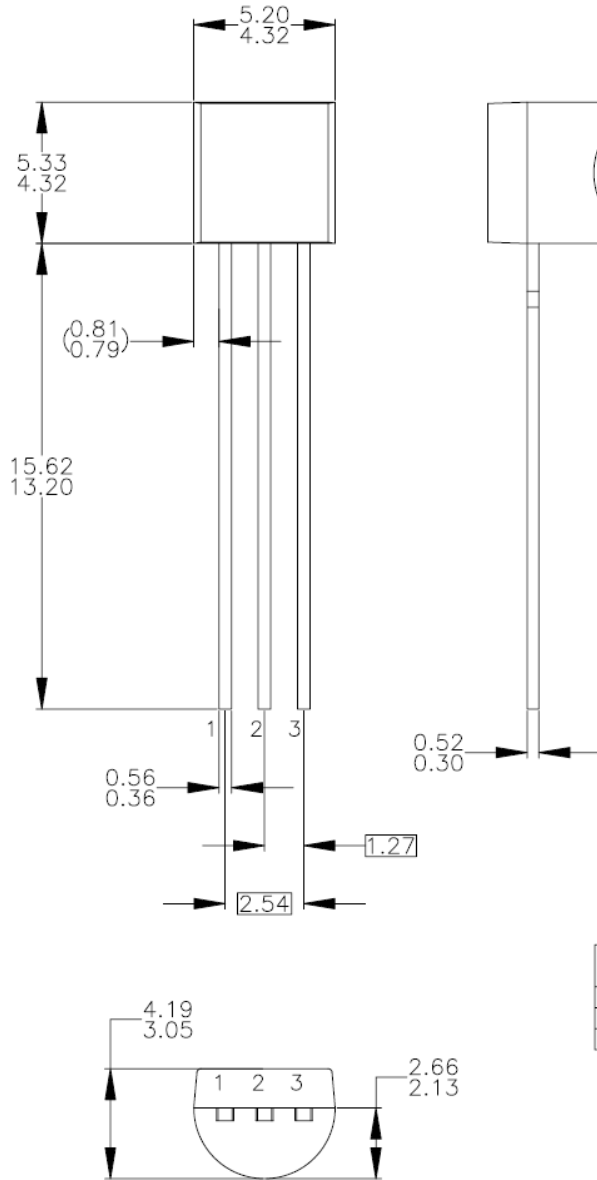
| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|-------------------------------------|--------------------------------------|--|------|------|------|-------|
| Off Characteristics | | | | | | |
| V_{CBO} | Collector-Base Breakdown Voltage | $I_C = -10\mu\text{A}, I_E = 0$ | -60 | | | V |
| V_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -1\text{mA}, I_B = 0$ | -50 | | | V |
| V_{EBO} | Emitter-Base Breakdown Voltage | $I_E = -10\mu\text{A}, I_C = 0$ | -5.0 | | | V |
| I_{CBO} | Collector Cut-off Current | $V_{CB} = -60\text{V}, I_E = 0$ | | | -100 | nA |
| I_{EBO} | Emitter Cut-off Current | $V_{EB} = -5\text{V}, I_C = 0$ | | | -100 | nA |
| On Characteristics | | | | | | |
| h_{FE} | DC Current Gain | $V_{CE} = -6\text{V}, I_C = -1\text{mA}$ | 90 | | 600 | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = -100\text{mA}, I_B = -10\text{mA}$ | -15 | | -300 | mV |
| $V_{BE(on)}$ | Base-Emitter On Voltage | $V_{CE} = -6\text{V}, I_C = -1\text{mA}$ | -580 | | -680 | mV |
| Small Signal Characteristics | | | | | | |
| f_T | Current Gain Bandwidth Product | $V_{CE} = -6\text{V}, I_C = -10\text{mA}$ | 50 | | | MHz |
| C_{ob} | Output Capacitance | $V_{CB} = -10\text{V}, I_E = 0$ $f = 1.0\text{MHz}$ | | | 6 | pF |
| NF | Noise Figure | $V_{CE} = -6\text{V}, I_C = -0.3\text{mA}$ $R_G = 10\text{k}\Omega, f = 100\text{Hz}$ | | | 20 | dB |

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$ **h_{FE} Classification**

| Classification | R | Q | P | K |
|----------------|----------|-----------|-----------|-----------|
| h_{FE} | 90 ~ 180 | 135 ~ 270 | 200 ~ 400 | 300 ~ 600 |

Physical Dimension

TO-92



NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994.
- D) TO-92 (92,94,96,97,98) PIN CONFIGURATION:

| PIN | 92 | | | 94 | | | 96 | | | 97 | | | 98 | | |
|-----|----|---|---|----|---|---|----|---|---|----|---|---|----|---|---|
| | P | F | M | P | F | M | P | F | M | P | F | M | P | F | M |
| 1 | E | S | S | E | S | S | B | D | G | C | G | D | C | G | D |
| 2 | B | D | G | C | G | D | E | S | S | B | D | G | E | S | S |
| 3 | C | G | D | B | D | G | C | G | D | E | S | S | B | D | G |

LEGEND:

P - BIPOLAR E - EMITTER D - DRAIN
F - JFET B - BASE S - SOURCE
M - DMOS C - COLLECTOR G - GATE







- E) FOR PACKAGE 92, 94, 96, 97 AND 98:
PIN CONFIGURATION DRAIN "D" AND SOURCE "S"
ARE INTERCHANGEABLE AT JFET "F" OPTION.
- F) DRAWING FILENAME: MKT-ZA03DREV3.

Dimensions in Millimeters



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| FastvCore™ | OPTOPLANAR® | SyncFET™ | VisualMax™ |
| FETBench™ |  ™ | Sync-Lock™ | XS™ |
| FlashWriter®* | PDP SPM™ |  ™* | |
| | Power-SPM™ | | |

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| Datasheet Identification | Product Status | Definition |
|--------------------------|-----------------------|---|
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